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FREE

GREEN (5-2008)



Vishay Semiconductors

Silicon Phototransistor in 0805 Package



DESCRIPTION

TEMT7100X01 is a silicon NPN epitaxial planar phototransistor with daylight blocking filter in a miniature, black 0805 package for surface mounting. Filter bandwidth is matched with 830 nm to 950 nm IR emitters.

FEATURES

- Package type: surface-mount
- Package form: 0805
- Dimensions (L x W x H in mm): 2 x 1.25 x 0.85
- AEC-Q101 qualified
- · High photo sensitivity
- Daylight blocking filter matches with 830 nm to 950 nm IR emitters
- Angle of half sensitivity: $\varphi = \pm 60^{\circ}$
- Package matched with IR emitter series VSMB1940X01
- Floor life: 168 h, MSL 3, according to J-STD-020
- Lead (Pb)-free reflow soldering
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

APPLICATIONS

- Detector in automotive applications
- · Photo interrupters
- Miniature switches
- Counters
- Encoders
- Position sensors

PRODUCT SUMMARY			
COMPONENT	I_{ca} (μA) at E _e = 1 mW/cm ² , λ = 950 nm, V_{CE} = 5 V	φ (°)	λ _{0.5} (nm)
TEMT7100X01	225 to 675	± 60	750 to 1010

Note

Test condition see table "Basic Characteristics"

ORDERING INFORMATION				
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM	
TEMT7100X01	Tape and reel	MOQ: 3000 pcs, 3000 pcs/reel	0805	

Note

MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Collector emitter voltage		V_{CEO}	20	V
Emitter collector voltage		V _{ECO}	7	V
Collector current		I _C	20	mA
Power power dissipation	T _{amb} ≤ 55 °C	P _V	100	mW
Junction temperature		Tj	100	°C
Operating temperature range		T _{amb}	-40 to +100	°C
Storage temperature range		T _{stg}	-40 to +100	°C
Soldering temperature	According to reflow profile Fig. 8	T _{sd}	260	°C
Thermal resistance junction-to-ambient	According to J-STD-051	R _{thJA}	270	K/W



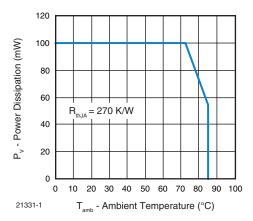


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Collector emitter breakdown voltage	$I_{C} = 0.1 \text{ mA}$	V_{CEO}	20	-	-	V
Collector dark current	V _{CE} = 5 V, E = 0	I _{CEO}	=	1	100	nA
Collector emitter capacitance	V _{CE} = 0 V, f = 1 MHz, E = 0	C _{CEO}	-	25	-	pF
Collector light current	E_e = 1 mW/cm ² , λ = 950 nm, V_{CE} = 5 V	I _{CA}	225	450	675	μΑ
Angle of half sensitivity		φ	=	± 60	-	0
Wavelength of peak sensitivity		λρ	-	870	-	nm
Range of spectral bandwidth		λ _{0.5}	-	750 to 1010	-	nm
Collector emitter saturation voltage	$I_{C} = 0.05 \text{ mA}$	V _{CEsat}	-	-	0.4	V
Temperature coefficient of Ica	$E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm}, V_{CE} = 5 \text{ V}$	Tk _{lca}	-	1.1	-	%/K

BASIC CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

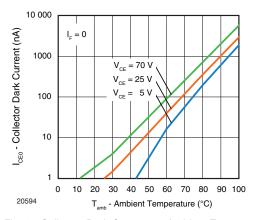


Fig. 2 - Collector Dark Current vs. Ambient Temperature

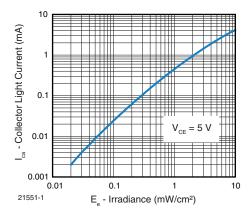


Fig. 3 - Collector Light Current vs. Irradiance



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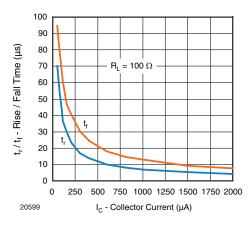


Fig. 4 - Rise/Fall Time vs. Collector Current

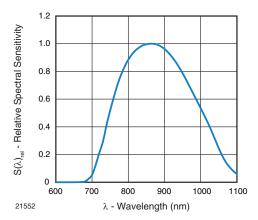


Fig. 5 - Relative Spectral Sensitivity vs. Wavelength

20° 30° rel. - Relative Radiant Intensity 40° 1.0 0.9 50° 8.0 60° 70° 0.7 80° 0.4 0.6 0.2 0 94 8013

Fig. 6 - Relative Radiant Sensitivity vs. Angular Displacement

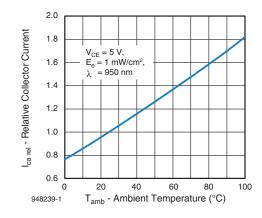


Fig. 7 - Relative Collector Current vs. Ambient Temperature

REFLOW SOLDER PROFILE

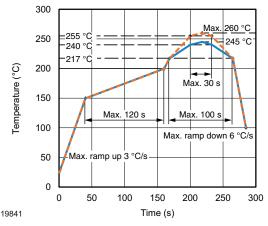


Fig. 8 - Lead (Pb)-free Reflow Solder Profile According to J-STD-020

DRYPACK

Devices are packed in moisture barrier bags (MBB) to prevent the products from moisture absorption during transportation and storage. Each bag contains a desiccant.

FLOOR LIFE

Floor life (time between soldering and removing from MBB) must not exceed the time indicated on MBB label:

Floor life: 168 h

Conditions: T_{amb} < 30 °C, RH < 60 %

Moisture sensitivity level 3, acc. to J-STD-020.

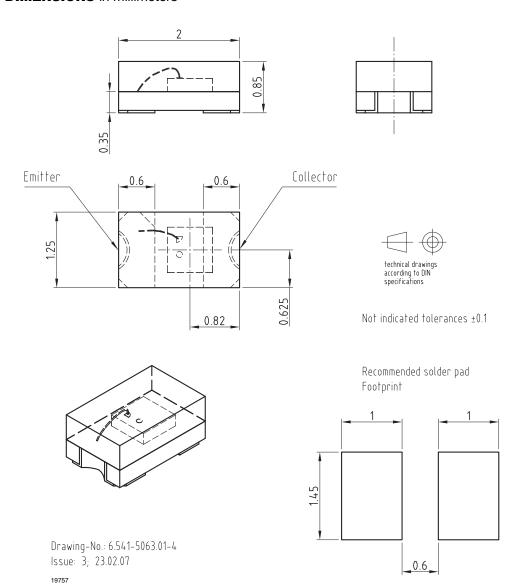
DRYING

In case of moisture absorption devices should be baked before soldering. Conditions see J-STD-033D or label. Devices taped on reel dry using recommended conditions 192 h at 40 $^{\circ}$ C (+ 5 $^{\circ}$ C), RH < 5 $^{\circ}$ M.



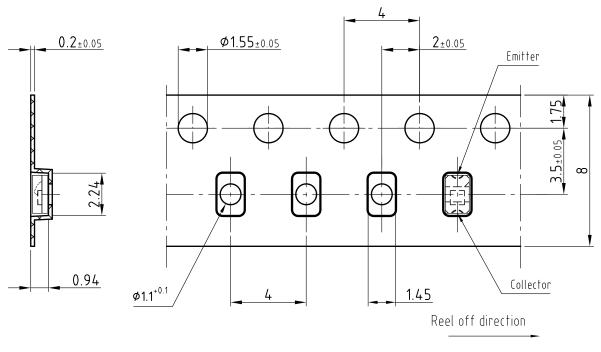
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PACKAGE DIMENSIONS in millimeters



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BLISTER TAPE DIMENSIONS in millimeters



Drawing-No.: 9.700-5310.01-4

Issue: 2; 14.08.07

20690

Not indicated tolerances ±0.1

Quantity per reel: 3000 pcs

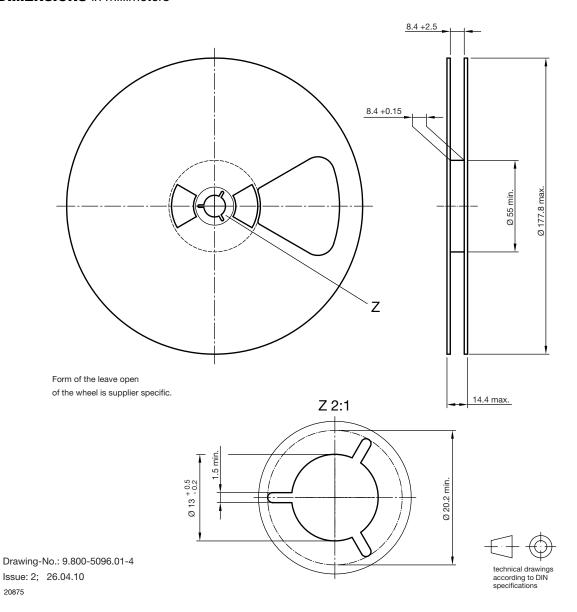


technical drawings according to DIN specifications

20875

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REEL DIMENSIONS in millimeters





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